TOSHIBA Field Effect Transistor Silicon P Channel MOS Type ( $L^2$ - $\pi$ -MOSV)

# 2SJ401

# DC-DC Converter, Relay Drive and Motor Drive Applications

• 4-V gate drive

• Low drain–source ON resistance :  $R_{DS(ON)} = 33 \text{ m}\Omega \text{ (typ.)}$ 

 $\bullet \quad \text{High forward transfer admittance} \quad : \mid Y_{fs} \mid = 20 \; \mathrm{S} \; (\text{typ.})$ 

• Low leakage current :  $IDSS = -100 \mu A (max) (VDS = -60 V)$ 

• Enhancement mode :  $V_{th} = -0.8 \text{ to } -2.0 \text{ V (V}_{DS} = -10 \text{ V}, I_D = -1 \text{ mA})$ 

## Absolute Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	-60	V
Drain-gate voltage (Ro	<sub>SS</sub> = 20 kΩ)	$V_{DGR}$	-60	V
Gate-source voltage		V <sub>GSS</sub>	±20	V
Drain current	DC (Note 1)	I <sub>D</sub>	-20	Α
	Pulse(Note 1)	I <sub>DP</sub>	-80	Α
Drain power dissipation	n (Tc = 25°C)	P <sub>D</sub>	100	W
Single pulse avalanche	e energy (Note 2)	E <sub>AS</sub>	800	mJ
Avalanche current		I <sub>AR</sub>	-20	Α
Repetitive avalenche e	nergy (Note 3)	E <sub>AR</sub>	10	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature ra	ange	T <sub>stg</sub>	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	1.25	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	83.3	°C/W

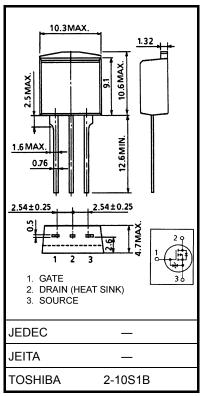
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD}$  = -50 V,  $T_{ch}$  = 25°C (initial), L = 1.44 mH,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = -20 A

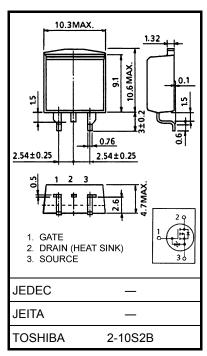
Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

Unit: mm



Weight: 1.5 g (typ.)



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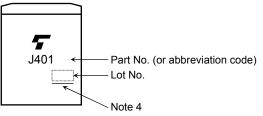
## **Electrical Characteristics (Ta = 25°C)**

Charao	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I <sub>GSS</sub>	V <sub>GS</sub> = ±16 V, V <sub>DS</sub> = 0 V	_	_	±10	μΑ
Drain cut-off cu	rrent	I <sub>DSS</sub>	V <sub>DS</sub> = -60 V, V <sub>GS</sub> = 0 V	_	_	-100	μΑ
Drain-source br	eakdown voltage	V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-60	_	_	V
Gate threshold	voltage	V <sub>th</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1 mA	-0.8	_	-2.0	V
Drain-source ON resistance		R <sub>DS (ON)</sub>	V <sub>GS</sub> = -4 V, I <sub>D</sub> = -10 A		50	90	0
			V <sub>GS</sub> = -10 V, I <sub>D</sub> = -10 A		33	45	mΩ
Forward transfe	r admittance	Y <sub>fs</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -10 A	10	20	_	S
Input capacitano	ce	C <sub>iss</sub>		_	2800	_	
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	450	_	pF
Output capacitance		Coss		_	1300	_	
Switching time	Rise time	t <sub>r</sub>	$V_{GS} = \frac{0V}{10V}$ $V_{OUT}$ $V_{DD} = -30V$ $V_{DD} = -30V$ $V_{DU} = 10 \mu s$	_	15	_	- ns
	Turn-on time	t <sub>on</sub>		_	35	_	
	Fall time	t <sub>f</sub>		_	25	_	
	Turn-off time	t <sub>off</sub>		_	120	_	
Total gate charge (Gate-source plus gate-drain)		Qg		_	90	_	
Gate-source charge		Q <sub>gs</sub>	$V_{DD} \approx -48 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -20 \text{ A}$		65	_	nC
Gate-drain ("miller") charge		Q <sub>gd</sub>			25	_	

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	_	_	_	-20	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	-80	Α
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = -20 A, V <sub>GS</sub> = 0 V	_	_	1.7	V
Reverse recovery time	t <sub>rr</sub>	I <sub>DR</sub> = -20 A, V <sub>GS</sub> = 0 V		75	_	ns
Reverse recovery charge	Qrr	dl <sub>DR</sub> / dt = 50 A / μs	_	83	_	nC

### Marking

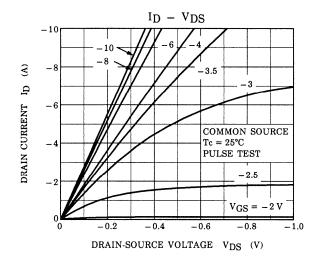


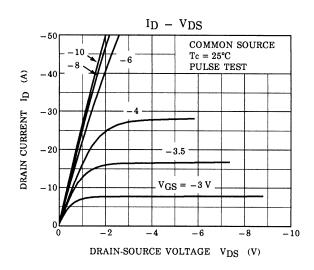
Note 4: A line under a Lot No. identifies the indication of product Labels.

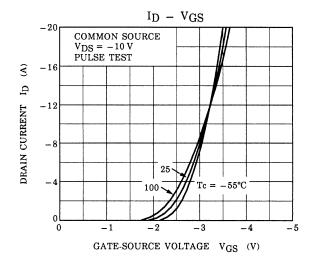
Not underlined: [[Pb]]/INCLUDES > MCV

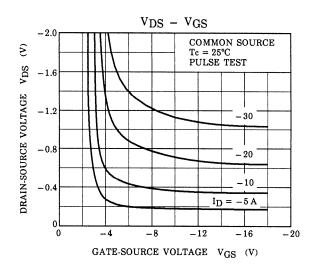
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

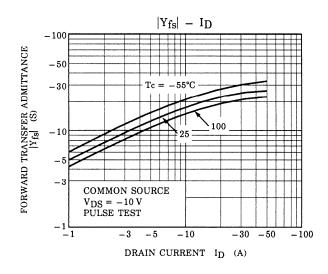
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

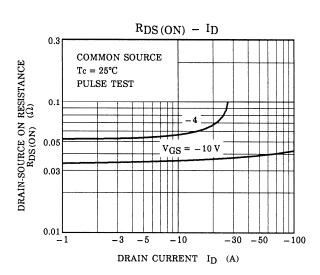




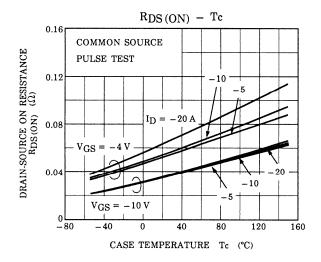


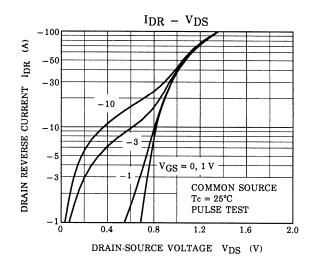


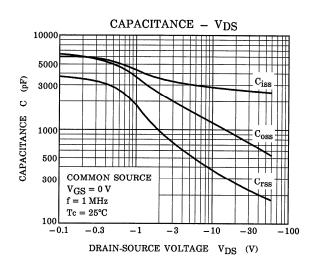


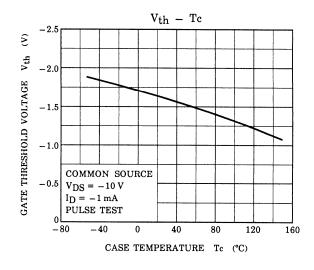


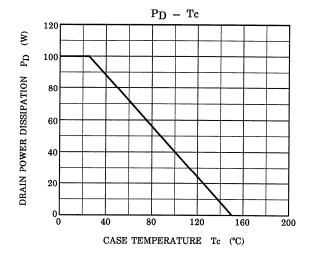
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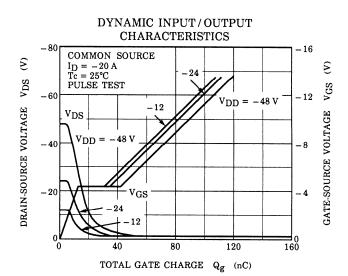




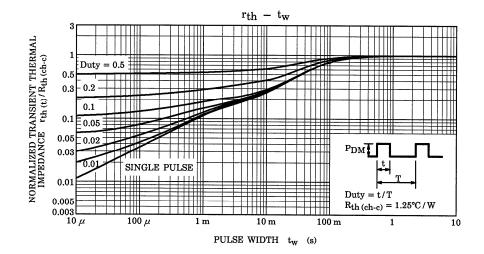


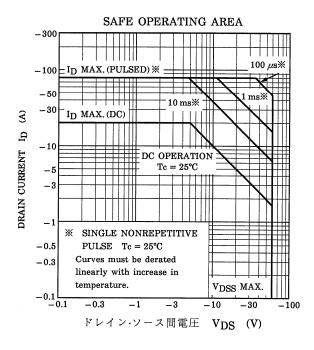


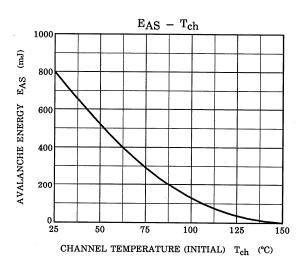


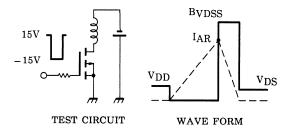


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$$\begin{array}{ll} R_{\mbox{\scriptsize G}}\!=\!25\Omega \\ V_{\mbox{\scriptsize DD}}\!=\!-50\mbox{\scriptsize V}, \; L\!=\!1.44\mbox{\scriptsize mH} \end{array} \qquad E_{\mbox{\scriptsize AS}}\!=\!\frac{1}{2}\cdot L\cdot I^2\cdot (\frac{B_{\mbox{\scriptsize VDSS}}}{B_{\mbox{\scriptsize VDSS}}\!-V_{\mbox{\scriptsize DD}}}) \label{eq:constraint}$$

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